

ABSTRACT OF THE DISCLOSURE

A crystal growth method, comprising the steps
of: a) bringing a nitrogen material into a reaction
vessel in which a mixed molten liquid comprising an
5 alkaline metal and a group-III metal; and b) growing a
crystal of a group-III nitride using the mixed molten
liquid and the nitrogen material brought in by the step
a) in the reaction vessel, wherein a provision is made
such as to prevent a vapor of the alkaline metal from
10 dispersing out of the reaction vessel.

09031648-101601